



[FD3] Plasma Assisted Process Monitoring Technologies	
Date / Time	July 27 (Fri.), 2018 / 14:30-17:00
Place	Room D (#115)
Session Chair(s)	Jung-Sik Yoon (NFRI, Korea)

FD3-1 [Invited] 14:30-15:00

Cutoff Probe for Process Monitoring

ShinJae You

Chungnam Nat'l Univ., Korea

FD3-2 15:00-15:20

Study of Plasma Diagnostics and Algorithm for Virtual Metrology in Etch Process Plasma

Jongsik Kim, Dae Chul Kim, Jung Ho Song, Yonghyun Kim, Young-Woo Kim, Duksun Han, Mi-Young Song, and Jung-Sik Yoon

NFRI, Korea

FD3-3 15:20-15:40

Development of Plasma Information Based Virtual Metrology to Trace the Drift of Plasma-Assisted Processes

Hyun-Joon Roh¹, Sangwon Ryu¹, Yunchang Jang¹, Nam-Kyun Kim¹, Younggil Jin², Seolhye Park², and Gon-Ho Kim¹

¹*Seoul Nat'l Univ., Korea*, ²*Samsung Display Co., Ltd., Korea*

FD3-4 15:40-16:00

Measurement of Electron Density of the Cutoff Probe in High Pressure Plasma

SiJun Kim¹, JangJae Lee¹, YoungSeok Lee¹, ChulHee Cho¹, SeungWan Yoo¹, JungHyung Kim², and ShinJae You¹

¹*Chungnam Nat'l Univ., Korea*, ²*KRISS, Korea*

FD3-5 16:00-16:20

Performance Evaluation Method of RF Generators with In-Situ Plasma Process Monitoring Sensors

Kyung Jae Jo, Syed Ashar Ali, and Sang Jeen Hong

Myongji Univ., Korea

FD3-6 16:20-16:40

A Linear Combination Model for Analyzing Long-Time Data Trend in a Plasma Etching Process

Moojin Kim, Gunpil Hwang, Seungjin Kim, and Yongjoon Cheong

Samsung Electronics Co., Ltd., Korea

FD3-7 16:40-17:00

Surrogate Modeling of Plasma System with Bayesian Deep Neural Network

Damdae Park and Jong Min Lee

Seoul Nat'l Univ., Korea